



Description

The SLD1450S is a 1450 nm broadband superluminescent diode (SLD). This SLD is housed in a butterfly package with a TEC and integrated thermistor that allow for temperature control, thus stabilizing the power and spectrum. The output is coupled to 1.5 m of single mode SMF-28e fiber terminated with an FC/APC connector.

Specifications

Absolute Maximum Ratings ^a	
Absolute Max Current	600 mA
Operating Case Temperature	0 to 70 °C
Storage Temperature	-10 to 70 °C
Pin Code	14 Pin, Type 1

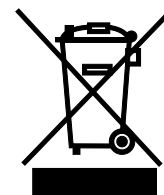
- a. Please note that exceeding the absolute maximum ratings above may cause device failure.

CW; $T_{CHIP} = 15 - 30\text{ °C}$, $T_{CASE} = 0 - 70\text{ °C}$

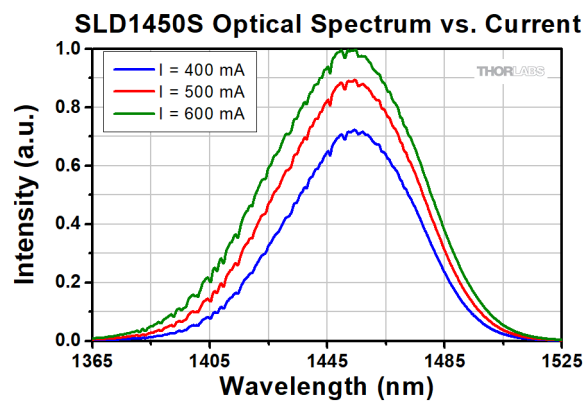
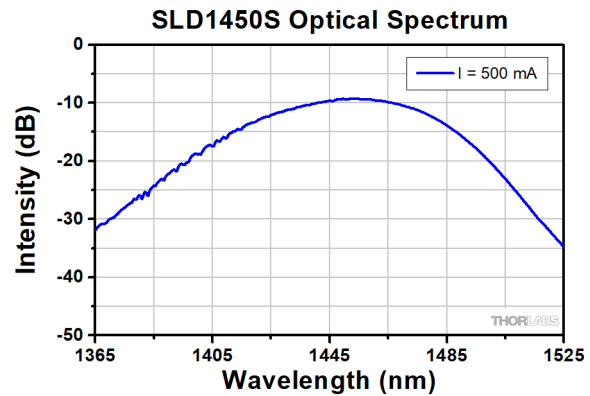
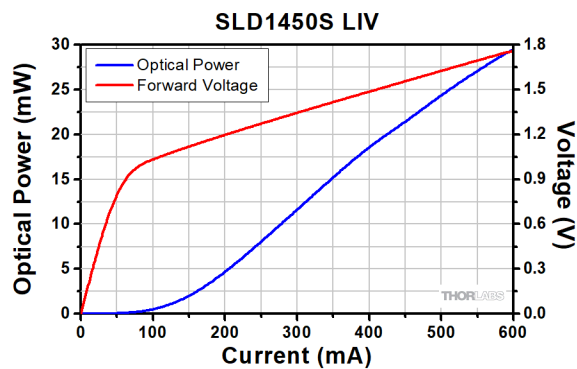
Operating Specifications ^a				
	Symbol	Min	Typical	Max
Center Wavelength ^b	λ_C	1435 nm	1450 nm	1465 nm
Operating Current	I_{OP}	-	500 mA	600 mA
ASE Power ^c	P_{ASE}	23 mW	25 mW	-
Optical 3 dB Bandwidth ^{c,d}	BW	50 nm	54 nm	-
Gain Ripple (RMS) ^c	δG	-	0.06 dB	0.35 dB
Forward Voltage ^c	V_F	-	1.7 V	2.0 V
TEC Operation (Typical / Max @ $T_{CASE} = 25\text{ °C} / 70\text{ °C}$)				
TEC Current	I_{TEC}	-	0.3 A	1.5 A
TEC Voltage	V_{TEC}	-	0.4 V	4.0 V
Thermistor Resistance	R_{TH}	-	10 k Ω	-

- a. These operating specifications are a consistent set of values which will yield the specified performance.
- b. The center wavelength for an SLD with a near-Gaussian spectral shape is defined by an average weighted by relative amplitude and may not correspond to the peak power or FWHM center wavelength.
- c. At Operating Current
- d. At the minimum ASE power, we guarantee the minimum 3 dB bandwidth.

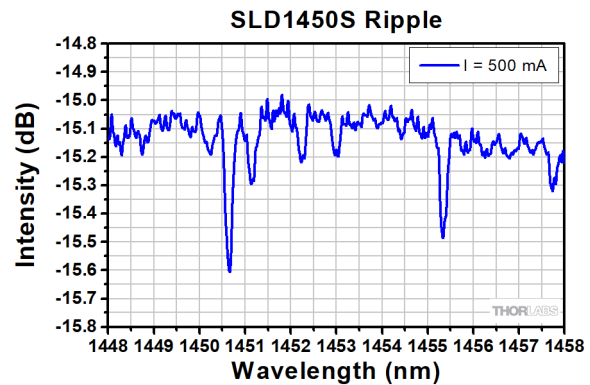
Fiber Specifications	
Fiber Type	SMF-28e
Mode Field Diameter	9.2 \pm 0.4 μ m at 1310 nm 10.4 \pm 0.5 μ m at 1550 nm
Numerical Aperture	0.14
Fiber Length	1.5 m \pm 0.05 m
Connector	FC/APC, 2.0 mm Narrow Key



Typical Performance Plots

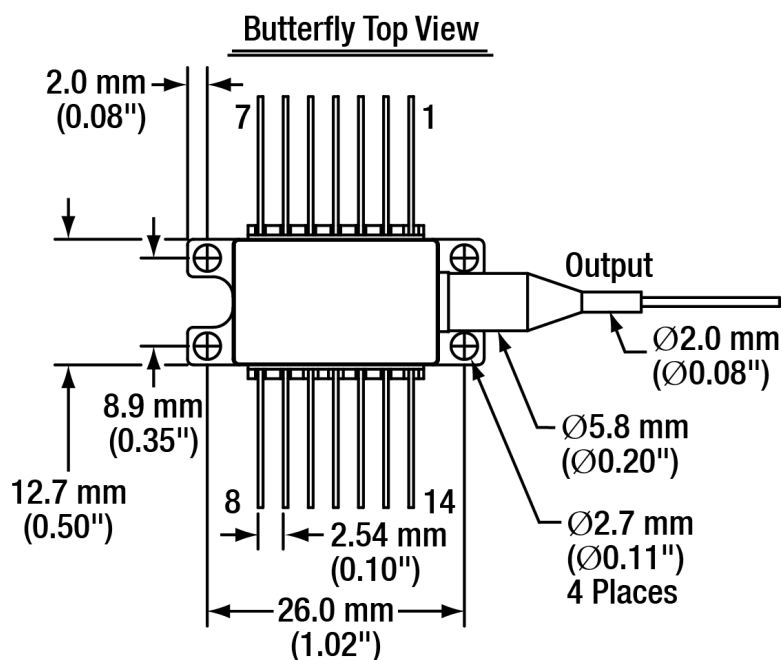


Note: As the current decreases, the bandwidth will decrease as well.



Note: The sharp dips in the spectrum are mostly caused by water absorption in the measurement setup. The resolution of the measurement was 0.1 nm.

Drawing



PIN IDENTIFICATION

1. TEC +	14. TEC -
2. Thermistor	13. Case Ground
3. NC	12. NC
4. NC	11. SLD Cathode
5. Thermistor	10. SLD Anode
6. NC	9. NC
7. NC	8. NC

